



# NMB2227A

40 V, 600 mA NPN/PNP general-purpose transistors

15 September 2016

Product data sheet

## 1. General description

NPN/PNP general-purpose transistors in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- General-purpose transistor
- High current
- Reduces component count on Printed-Circuit Board (PCB)
- Reduces pick and place costs
- AEC-Q101 qualified

## 3. Applications

- General-purpose switching and amplification
- Complementary driver
- Half-bridge and full-bridge driver

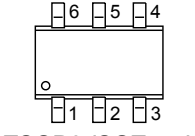
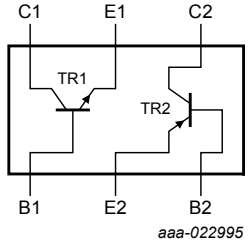
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>TR1 (NPN)</b>						
$V_{CEO}$	collector-emitter voltage	open base	-	-	40	V
$h_{FE}$	DC current gain	$V_{CE} = 10\text{ V}; I_C = 150\text{ mA}; \text{pulsed}; t_p \leq 300\ \mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	100	-	300	
<b>TR2 (PNP)</b>						
$V_{CEO}$	collector-emitter voltage	open base	-	-	-60	V
$h_{FE}$	DC current gain	$V_{CE} = -10\text{ V}; I_C = -150\text{ mA}; \text{pulsed}; t_p \leq 300\ \mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	100	-	300	
<b>Per transistor; for the PNP transistor with negative polarity</b>						
$I_C$	collector current		-	-	600	mA

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B1	base TR1	 <p>TSOP6 (SOT457)</p>	 <p>aaa-022995</p>
2	E2	emitter TR2		
3	B2	base TR2		
4	C2	collector TR2		
5	E1	emitter TR1		
6	C1	collector TR1		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
NMB2227A	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457

## 7. Marking

Table 4. Marking codes

Type number	Marking code
NMB2227A	3B

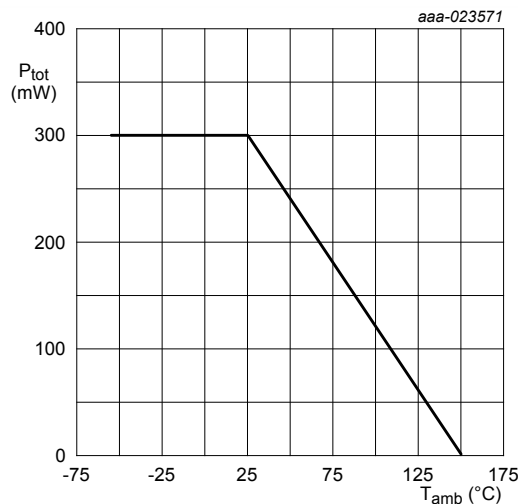
## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
<b>TR1 (NPN)</b>					
$V_{CBO}$	collector-base voltage	open emitter	-	75	V
$V_{CEO}$	collector-emitter voltage	open base	-	40	V
<b>TR2 (PNP)</b>					
$V_{CBO}$	collector-base voltage	open emitter	-	-60	V
$V_{CEO}$	collector-emitter voltage	open base	-	-60	V
<b>Per transistor; for the PNP transistor with negative polarity</b>					
$V_{EBO}$	emitter-base voltage	open collector	-	6	V
$I_C$	collector current		-	600	mA
$I_{CM}$	peak collector current	single pulse; $t_p \leq 1$ ms	-	800	mA
$I_{BM}$	peak base current		-	200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	200	mW
<b>Per device</b>					
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	300	mW
$T_j$	junction temperature		-	150	°C
$T_{amb}$	ambient temperature		-55	150	°C
$T_{stg}$	storage temperature		-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



FR4 PCB; standard footprint

**Fig. 1. Power derating curve**

## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Per transistor</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
<b>Per device</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>TR1 (NPN)</b>						
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 60\text{ V}; I_E = 0\text{ A}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	10	nA
		$V_{CB} = 60\text{ V}; I_E = 0\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	-	10	$\mu\text{A}$
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 5\text{ V}; I_C = 0\text{ A}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	10	nA
$h_{FE}$	DC current gain	$V_{CE} = 10\text{ V}; I_C = 1\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	50	-	-	
		$V_{CE} = 10\text{ V}; I_C = 10\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	75	-	-	
		$V_{CE} = 10\text{ V}; I_C = 150\text{ mA}; \text{pulsed}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	100	-	300	
		$V_{CE} = 10\text{ V}; I_C = 500\text{ mA}; \text{pulsed}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	40	-	-	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 150\text{ mA}; I_B = 15\text{ mA}; \text{pulsed}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	300	mV
		$I_C = 500\text{ mA}; I_B = 50\text{ mA}; \text{pulsed}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	1	V
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 150\text{ mA}; I_B = 15\text{ mA}; \text{pulsed}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	0.6	-	1.2	V
		$I_C = 500\text{ mA}; I_B = 50\text{ mA}; \text{pulsed}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	2	V
$t_d$	delay time	$I_C = 150\text{ mA}; I_{Bon} = 15\text{ mA}; I_{Boff} = -15\text{ mA}; V_{CC} = 10\text{ V}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	15	ns
$t_r$	rise time		-	-	20	ns
$t_{on}$	turn-on time		-	-	35	ns
$t_s$	storage time		-	-	200	ns
$t_f$	fall time		-	-	60	ns
$t_{off}$	turn-off time		-	-	250	ns
$C_C$	collector capacitance		$V_{CB} = 10\text{ V}; I_E = 0\text{ A}; i_e = 0\text{ A}; f = 1\text{ MHz}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	8
$C_E$	emitter capacitance	$V_{EB} = 500\text{ mV}; I_C = 0\text{ A}; i_c = 0\text{ A}; f = 1\text{ MHz}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	25	pF
$f_T$	transition frequency	$V_{CE} = 20\text{ V}; I_C = 20\text{ mA}; f = 100\text{ MHz}; T_{amb} = 25\text{ }^\circ\text{C}$	300	-	-	MHz
<b>TR2 (PNP)</b>						
$I_{CBO}$	collector-base cut-off current	$V_{CB} = -50\text{ V}; I_E = 0\text{ A}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	-10	nA
		$V_{CB} = -50\text{ V}; I_E = 0\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	-	-10	$\mu\text{A}$
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = -5\text{ V}; I_C = 0\text{ A}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	-50	nA
$h_{FE}$	DC current gain	$V_{CE} = -10\text{ V}; I_C = -0.1\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	75	-	-	
		$V_{CE} = -10\text{ V}; I_C = -1\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	100	-	-	
		$V_{CE} = -10\text{ V}; I_C = -10\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	100	-	-	

40 V, 600 mA NPN/PNP general-purpose transistors

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
		$V_{CE} = -10\text{ V}; I_C = -150\text{ mA}; \text{pulsed}; t_p \leq 300\ \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	100	-	300	
		$V_{CE} = -10\text{ V}; I_C = -500\text{ mA}; \text{pulsed}; t_p \leq 300\ \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	50	-	-	
$V_{CE\text{sat}}$	collector-emitter saturation voltage	$I_C = -150\text{ mA}; I_B = -15\text{ mA}; \text{pulsed}; t_p \leq 300\ \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-	-400	mV
		$I_C = -500\text{ mA}; I_B = -50\text{ mA}; \text{pulsed}; t_p \leq 300\ \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-	-1.6	V
$V_{BE\text{sat}}$	base-emitter saturation voltage	$I_C = -150\text{ mA}; I_B = -15\text{ mA}; \text{pulsed}; t_p \leq 300\ \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-	-1.3	V
		$I_C = -500\text{ mA}; I_B = -50\text{ mA}; \text{pulsed}; t_p \leq 300\ \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-	-2.6	V
$t_d$	delay time	$I_C = -150\text{ mA}; I_{B\text{on}} = -15\text{ mA}; I_{B\text{off}} = 15\text{ mA}; V_{CC} = -10\text{ V}; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-	12	ns
$t_r$	rise time		-	-	30	ns
$t_{\text{on}}$	turn-on time		-	-	40	ns
$t_s$	storage time		-	-	300	ns
$t_f$	fall time		-	-	65	ns
$t_{\text{off}}$	turn-off time		-	-	365	ns
$C_C$	collector capacitance	$V_{CB} = -10\text{ V}; I_E = 0\text{ A}; i_e = 0\text{ A}; f = 1\text{ MHz}; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-	8	pF
$C_E$	emitter capacitance	$V_{EB} = -2\text{ V}; I_C = 0\text{ A}; i_c = 0\text{ A}; f = 1\text{ MHz}; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-	30	pF
$f_T$	transition frequency	$V_{CE} = -20\text{ V}; I_C = -50\text{ mA}; f = 100\text{ MHz}; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	200	-	-	MHz

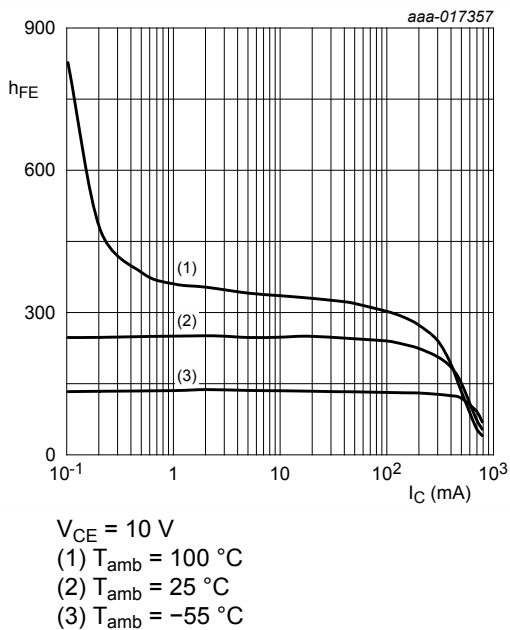


Fig. 2. NPN transistor: DC current gain as a function of collector current; typical values

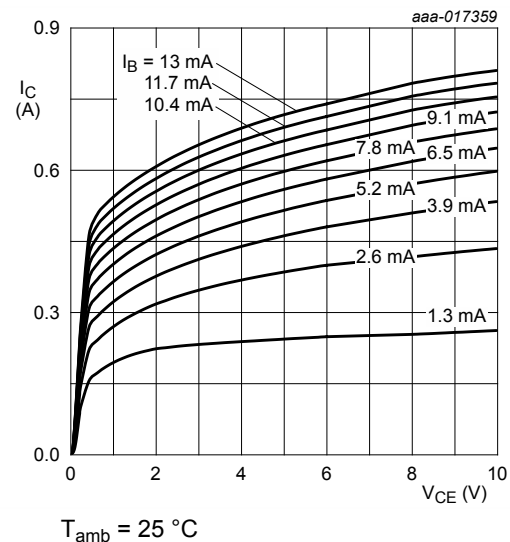
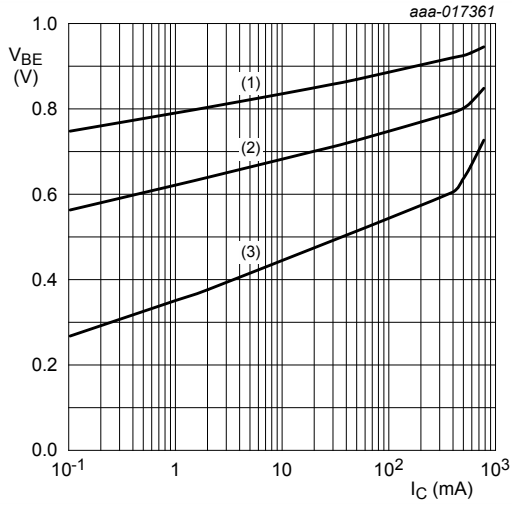
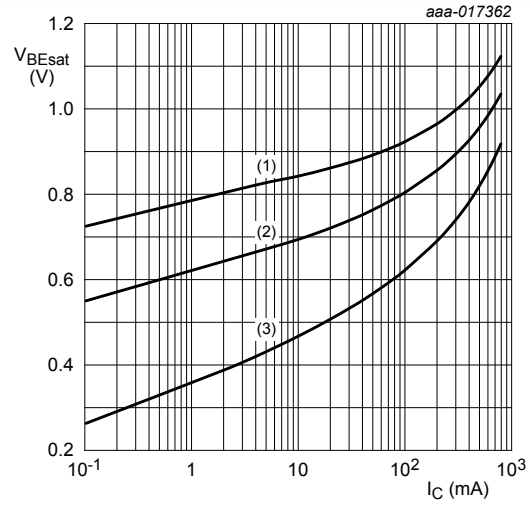


Fig. 3. NPN transistor: Collector current as a function of collector-emitter voltage; typical values



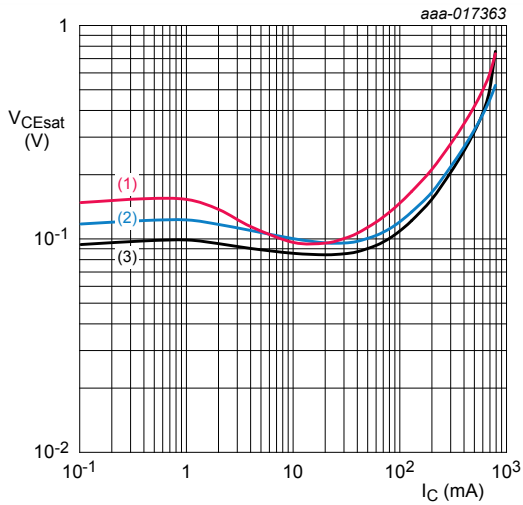
$V_{CE} = 10\text{ V}$   
 (1)  $T_{amb} = -55\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = 150\text{ °C}$

**Fig. 4. NPN transistor: Base-emitter voltage as a function of collector current; typical values**



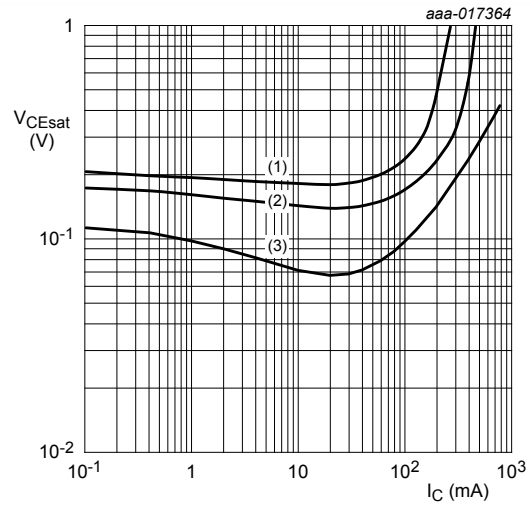
$I_C/I_B = 10$   
 (1)  $T_{amb} = -55\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = 150\text{ °C}$

**Fig. 5. NPN transistor: Base-emitter saturation voltage as a function of collector current; typical values**



$I_C/I_B = 20$   
 (1)  $T_{amb} = 150\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

**Fig. 6. NPN transistor: Collector-emitter saturation voltage as a function of collector current; typical values**



$T_{amb} = 25\text{ °C}$   
 (1)  $I_C/I_B = 100$   
 (2)  $I_C/I_B = 50$   
 (3)  $I_C/I_B = 10$

**Fig. 7. NPN transistor: Collector-emitter saturation voltage as a function of collector current; typical values**

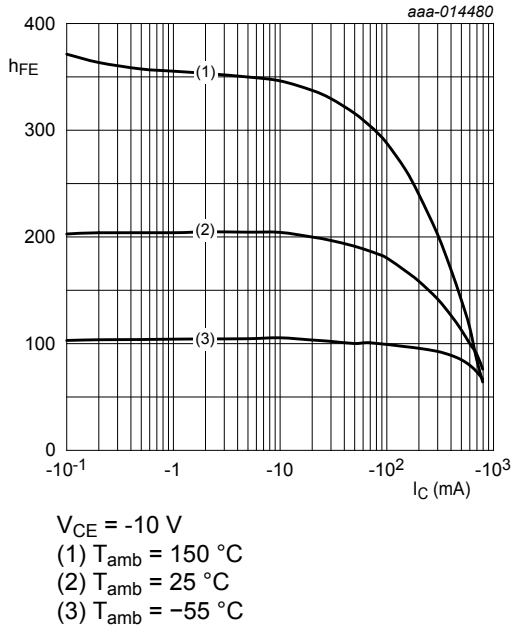


Fig. 8. PNP transistor: DC current gain as a function of collector current; typical values

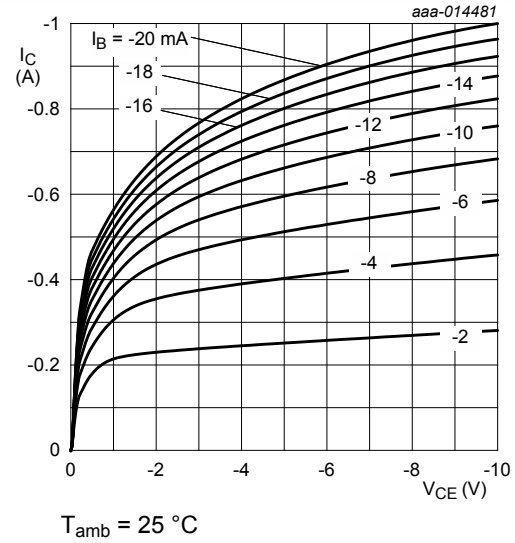


Fig. 9. PNP transistor: Collector current as a function of collector-emitter voltage; typical values

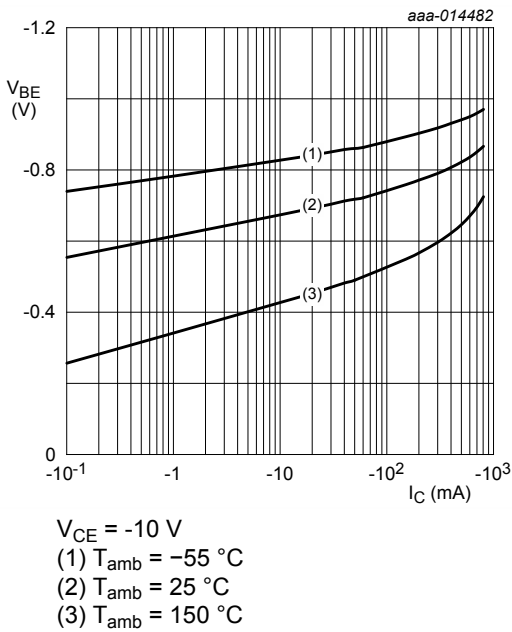


Fig. 10. PNP transistor: Base-emitter voltage as a function of collector current; typical values

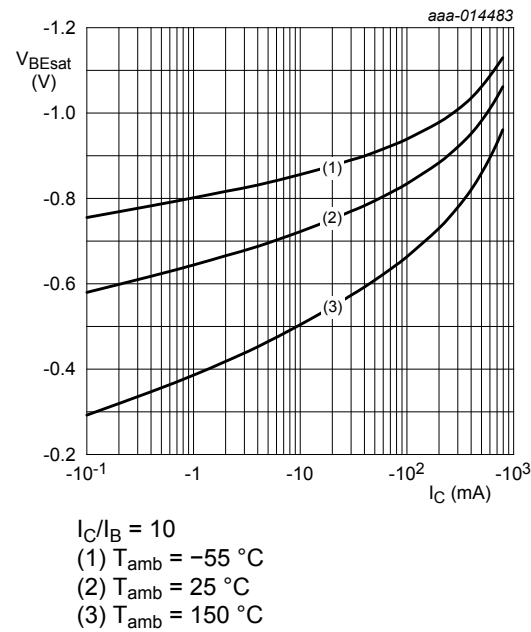
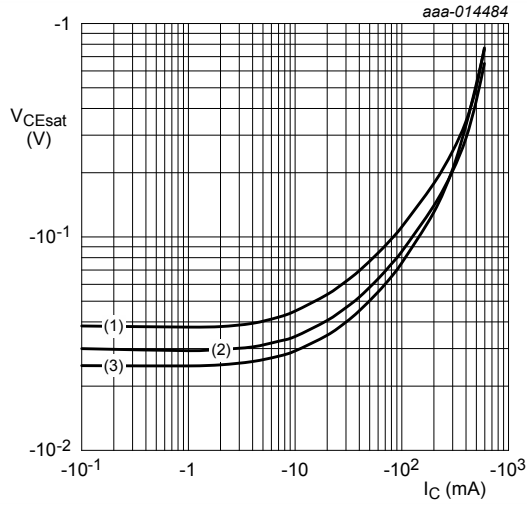


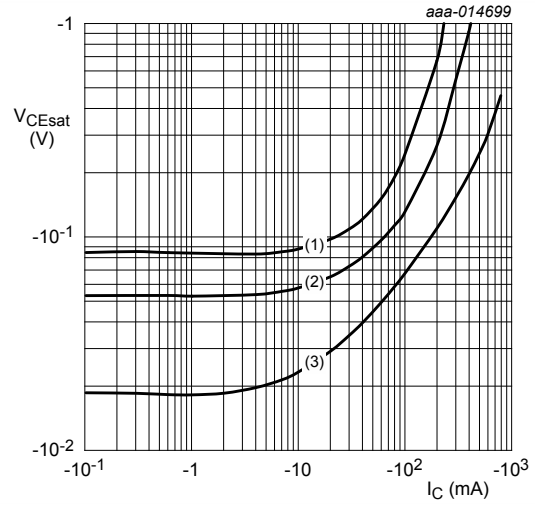
Fig. 11. PNP transistor: Base-emitter saturation voltage as a function of collector current; typical values





$I_C/I_B = 20$   
 (1)  $T_{amb} = 150\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

**Fig. 12. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values**



$T_{amb} = 25\text{ °C}$   
 (1)  $I_C/I_B = 100$   
 (2)  $I_C/I_B = 50$   
 (3)  $I_C/I_B = 10$

**Fig. 13. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values**

### 11. Test information

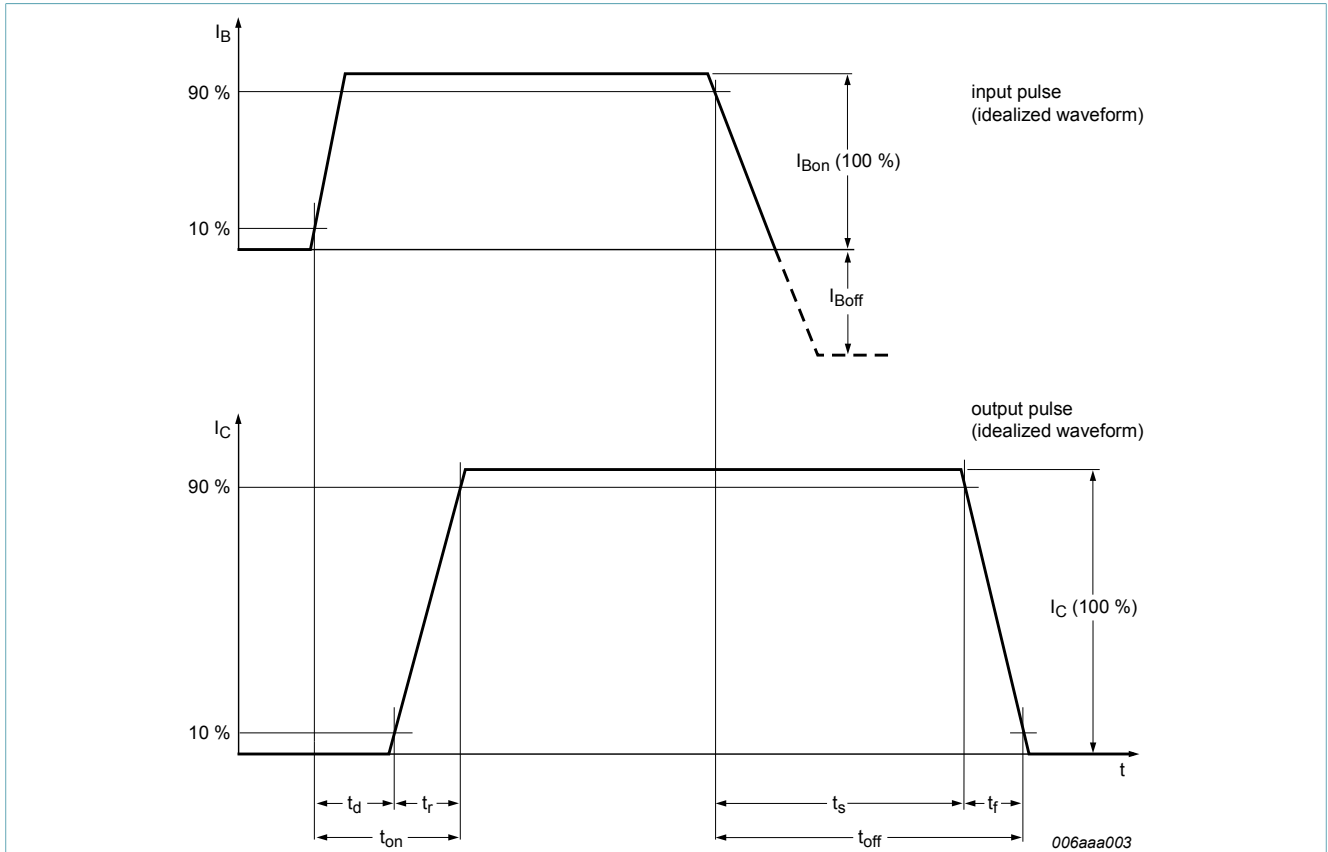


Fig. 14. TR1 (NPN): Transistor switching time definition

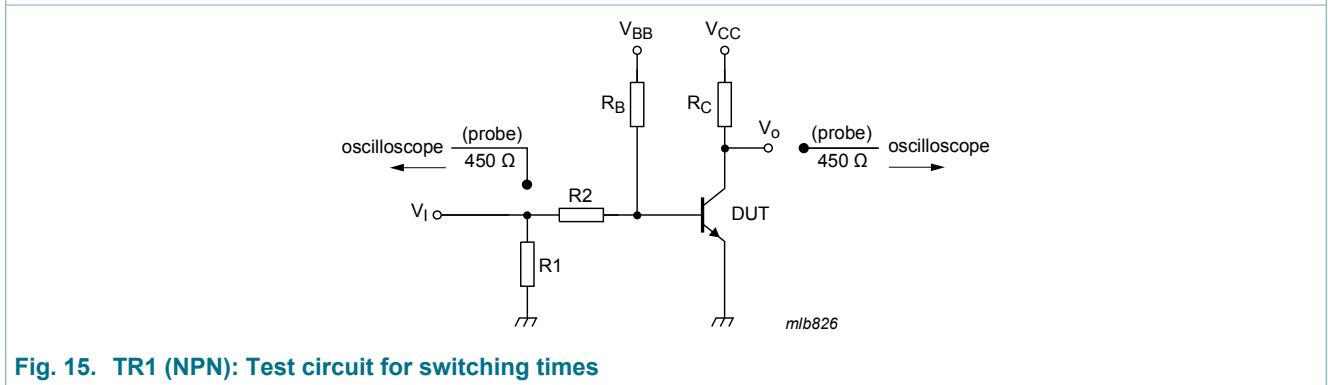


Fig. 15. TR1 (NPN): Test circuit for switching times

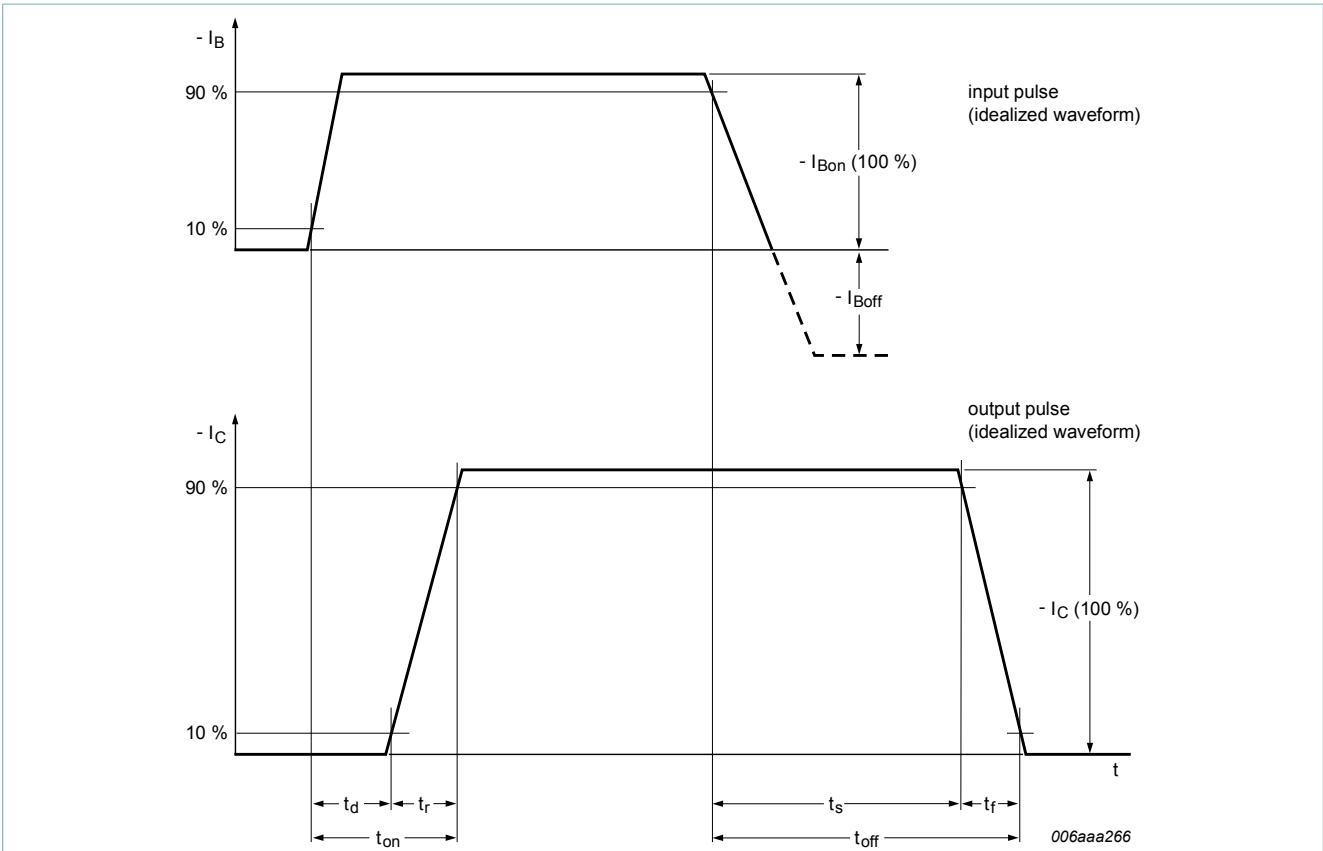


Fig. 16. TR2 (PNP): Transistor switching time definition

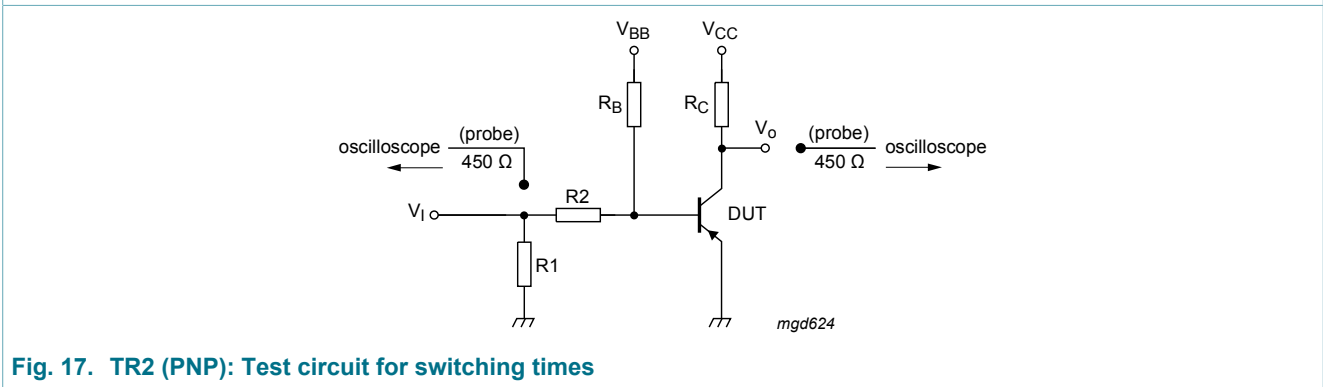


Fig. 17. TR2 (PNP): Test circuit for switching times

**Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline

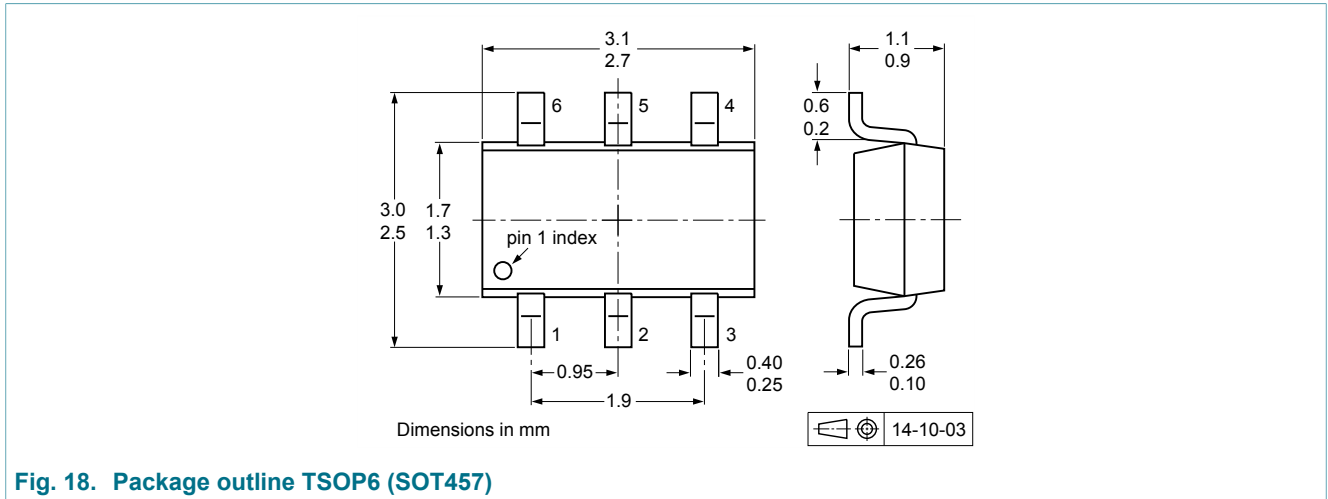


Fig. 18. Package outline TSOP6 (SOT457)

## 13. Soldering

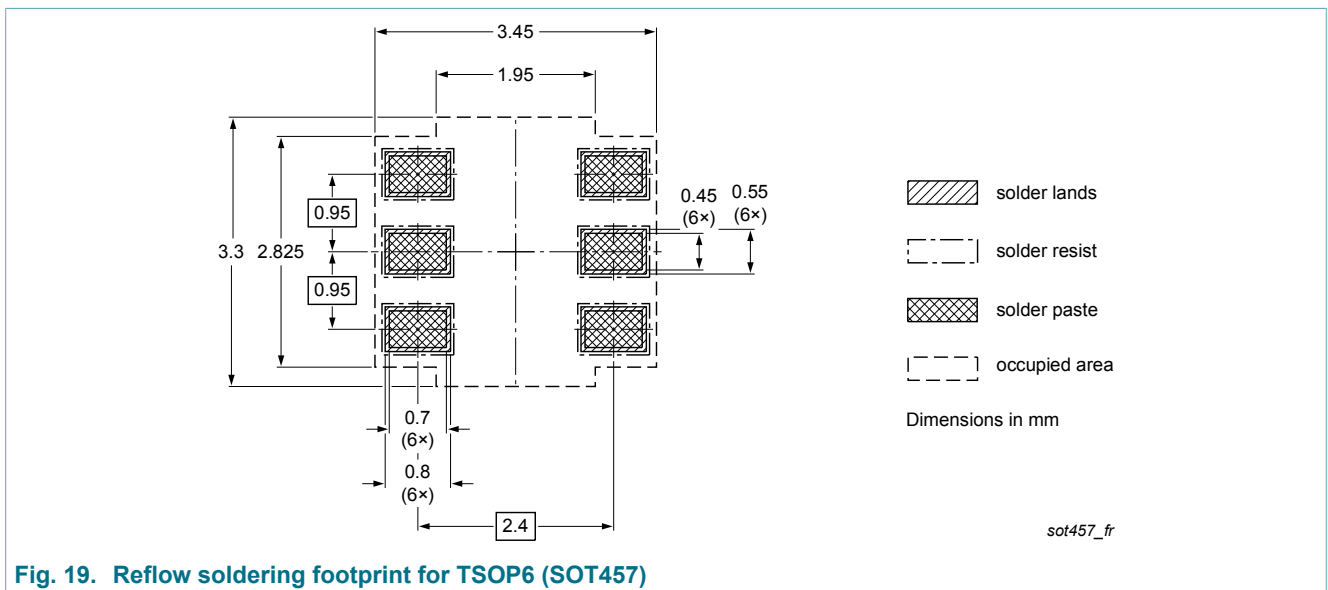


Fig. 19. Reflow soldering footprint for TSOP6 (SOT457)



## 14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NMB2227A v.1	20160915	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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